

10/630,280

UNITED STATES PATENT AND TRADEMARK OFFICE  
**CERTIFICATE OF CORRECTION**

PATENT NO. : 6,784,063 B2  
DATED : August 31, 2004  
INVENTOR(S) : Jac-Han Cha

Page 1 of 1

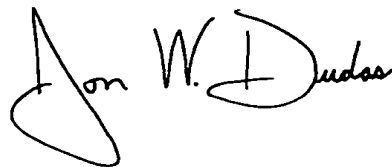
It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 5,

Lines 15-16, after "forming a nitride film for a spacer on," please delete "oxide film 64 for the base spacer;" and insert -- the structure generated by the above formations; -- in its place.

Signed and Sealed this

Fifteenth Day of February, 2005



JON W. DUDAS  
*Director of the United States Patent and Trademark Office*